



PCS CDMA LNA / Downconverter 1.8—2.0 GHz

Features

- High Integrated LNA and Downconverter
- Operates over 2.7 V to 5V Supply Voltage
- Low Noise Figure < 2.7 dB
- High Input Intercept Point -12 dBm
- Optional Control of LNA IP₃
- Low LO Drive Level -10 dBm
- Operates in US and Korean PCS Bands
- Miniature TSSOP-16 Plastic Package

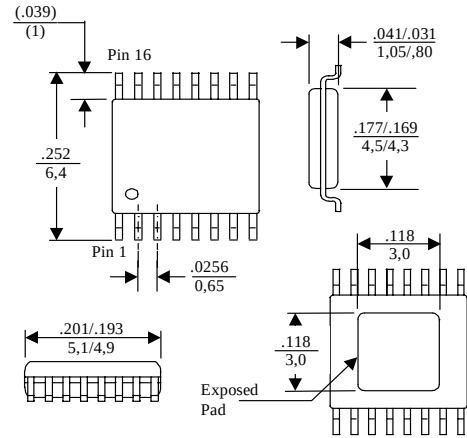
Description

M/A-COM's MD59-0021 is a fully integrated downconverter IC with LNA, RF amplifier, downconverting mixer, IF amplifier and LO buffer amplifier in a miniature TSSOP-16 plastic package with exposed metal lead frame backside for improved high frequency grounding.

The MD59-0021 is ideally suited for CDMA handset applications where wide dynamic range and low power consumption are important receiver requirements.

The MD59-0021 is fabricated using a M/A-COM's 0.5 micron low noise E/D GaAs MESFET process. The process features full passivation for increased performance and reliability.

TSSOP-16 Plastic Package¹



1. Dimensions are: in / mm

Ordering Information

Part Number	Package
MD59-0021TR	Forward Tape and Reel ¹
MD59-0021RTR	Reverse Tape and Reel ¹
MD59-0021SMB	Sample Board

1. If specific reel size is required, consult factory for part number assignment.

Electrical Specifications T_A = 25°C, V_{DD} = 3.0V, RF = 1.9 GHz, LO = 1.69 GHz

Parameter	Test Conditions	Units	Min.	Typ.	Max.
Low Noise Amplifier					
Gain	Frequency = 1.9 GHz	dB		14	
Noise Figure		dB		1.8	
VSWR In/Out				2:1	
Input IP ₃		dBm		+6	
I _{DD}		mA		13	
Complete DownConverter¹					
Conversion Gain		dB		22.5	25.4
Noise Figure	RF = 1.9 GHz	dB		2.7	
Input IP ₃	LO = 1.69 GHz, LO Level = -10 dBm	dBm		-12	
LO-to-RF Isolation		dB		50	
LO-to-IF Isolation		dB		24	
I _{DD}	IF = 210 MHz	mA		32	

1. Complete downconverter measurements taken with 3 dB pad between LNA output and RFA input.

Specifications subject to change without notice.

V 2.0

■ **North America:** Tel. (800) 366-2266, Fax (800) 618-8883
 ■ **Asia/Pacific:** Tel. +81-44-844-8296, Fax +81-44-844-8298
 ■ **Europe:** Tel. +44 (1344) 869 595, Fax +44 (1344) 300 020

Visit www.macom.com for additional data sheets and product information.

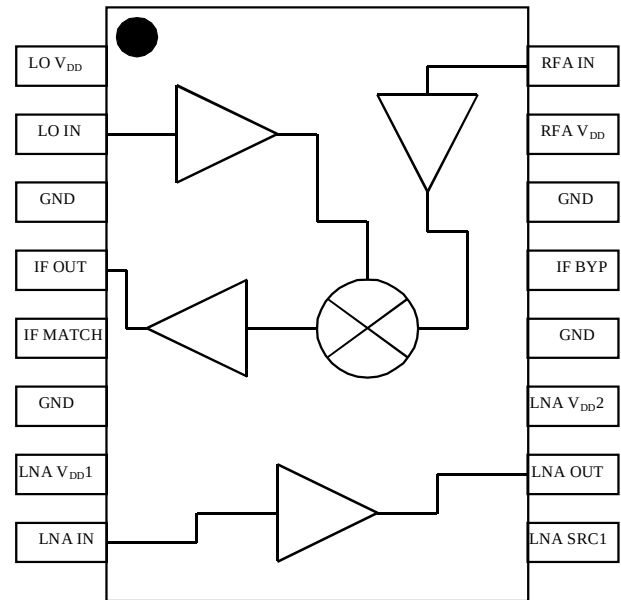
tyco / Electronics



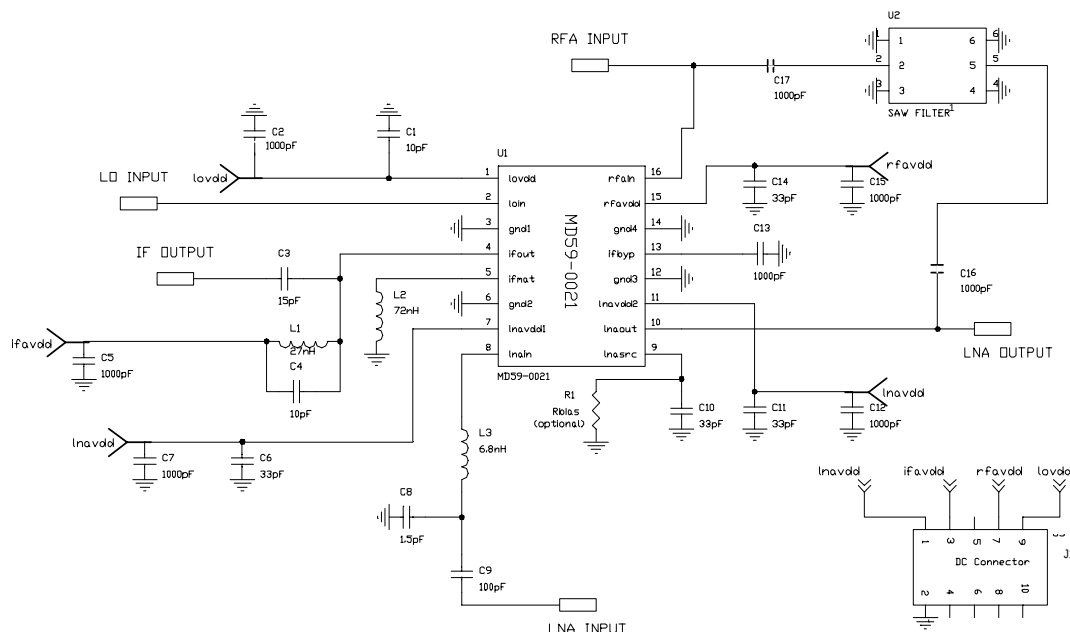
Pin Configuration

PIN No.	PIN	Description
1	LO V _{DD}	LO Amplifier Supply Voltage. RF bypassing required.
2	LO In	Local Oscillator Input (-10 to -7 dBm) (DC blocked)
3	GND	DC and RF ground
4	IF Out	IF Output and Downconverter - must be externally matched to input impedance of IF Filter.
5	IF Match	Matching between I FA and Mixer - requires an inductor to ground.
6	GND	DC and RF ground
7	LNA V _{DD1}	LNA Stage 1 supply voltage. RF bypassing required.
8	LNA In	RF Input to LNA. External matching required.
9	LNA SRC	Source of LNA output stage FET. RF bypassing required. Off-chip resistor may be used to increase IP ₃ .
10	LNA Out	50Ω Output of LNA. (DC Blocked)
11	LNA V _{DD2}	LNA Stage 2 supply voltage. RF bypassing required.
12	GND	DC and RF ground.
13	IF BYP	IF Bypass of Mixer. Required DC block and RF/IF ground.
14	GND	DC and RF ground
15	RFA V _{DD}	RFA supply voltage. RF bypassing required.
16	RFA In	50Ω Input of RFA. (DC blocking required)

Block Diagrams



Sample Board Schematic



1. Saw filter characteristics to be determined by customer, depending on band of operation. Sample boards are supplied with 3 dB pi pad installed in place of saw filter, to emulate typical worst case loss. Data supplied with sample board is measured over US PCS1900 Rx Band.

Specifications subject to change without notice.

V 2.0

North America: Tel. (800) 366-2266, Fax (800) 618-8883
Asia/Pacific: Tel. +81-44-844-8296, Fax +81-44-844-8298
Europe: Tel. +44 (1344) 869 595, Fax +44 (1344) 300 020

Visit www.macom.com for additional data sheets and product information.

tyco Electronics

MACOM

External Circuitry Parts List

Ref. Designation	Value	Purpose
C6, C10, C11, C14	33 pF	RF Bypass
C2, C5, C7, C12, C13, C15-C17	1000 pF	RF / IF Bypass
C3	15 pF	IF Matching
C1, C4	10 pF	Bypass, IF Matching
C8	1.5 pF	LNA Input Matching
C9	100 pF	RF Bypass
L1	27 nH	IF Matching
L2	72 nH	IF Amplifier Input Matching
L3	6.8 nH	LNA Input Matching
R1	R_{bias}	Optional resistor to increase bias current in LNA
U1		MD59-00021 LNA/Downconverter
U2	Saw Filter	Filter TX signals and image
J1	DC Connect	10 PIN DC Connector

Operating Instructions

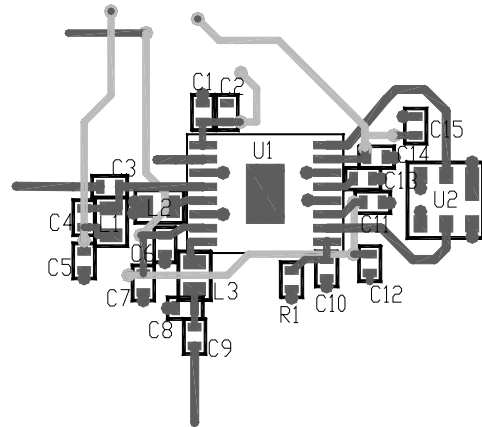
The MD59-0021 is a highly integrated MMIC downconverter for the 1.8-2 GHz PCS band. The downconverter provides exceptional RF performance while consuming low DC current and is packaged in a low cost plastic package. It is ideal for light weight battery operated portable radio systems.

The receive chain consists of an LNA, RFA, balanced mixer and single-ended IF output buffer amplifier as shown in the block diagram. Surface mount resistors, inductors and capacitors are used in conjunction with the IC for optimum performance, tunability and ease of use. A schematic showing the IC and required external components is shown on the previous page.

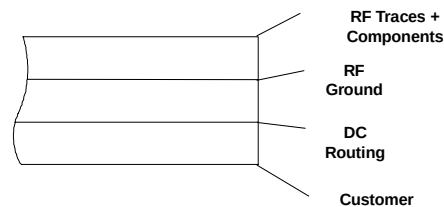
The input of the LNA is matched externally with a series inductor (L3) and a shunt capacitor (C8) to provide a low loss match to the optimum noise impedance in the band of interest. A high Q inductor such as Coilcraft's 0603CS series must be used if the specified noise figures are to be achieved. The series capacitor C9 is a DC blocking capacitor whose value is not critical (it should be $\geq 100\text{pF}$). The LNA is nominally biased with 13 mA to give an input IP3 of +6 dBm. An external resistor R1, may be used to increase the LNA bias current and thus increase the IP3. An external image reject filter is required between the LNA output and RFA input to prevent downconversion of noise at the image frequency to the IF. This filter should have a 50 Ω input and output impedance.

The mixer is a balanced resistive FET mixer which provides exceptional linearity and isolation with low loss and no DC current. An off-chip inductor, L, is required to match the output of the mixer to the input of the IF buffer amplifier.

Recommended PCB Configuration



Cross Section View



The IF output port is the open drain of the IF buffer amplifier. This allows maximum flexibility of intermediate frequency and also IF filter characteristics. A matching network such as that shown on page 2 can be used to match from the output impedance of the buffer to the input impedance of the filter at the required frequency. The inductor also acts as a choke for the DC supply line.

The LO input port is internally matched to 50 Ω . An LO buffer amplifier amplifies the -10 dBm input signal to the level required to drive the mixer. Performance is optimum with a drive level of -5 dBm.

All DC supply lines must be properly bypassed at RF frequencies to obtain optimum performance and at lower frequency to maintain unconditional stability. Capacitors C1, C6, C11 and C14 are RF bypass capacitors for the LNA, RFA and LOA. The value and placement of these capacitors are critical in determining the frequency response of these amplifiers. Capacitor C10 is a source bypass capacitor for the second stage of the low noise amplifier. The placement of this capacitor will affect the gain of the LNA. For best performance, all the RF bypass capacitors should be placed as shown in the PCB drawing shown above. Capacitors C2, C5, C7, C12, C13 and C15 are 1000 pF low frequency DC supply bypass capacitors. Their value and placement are less critical than the other capacitors. However, for best results, these capacitors should be located as close to the package leads as possible.

Specifications subject to change without notice.

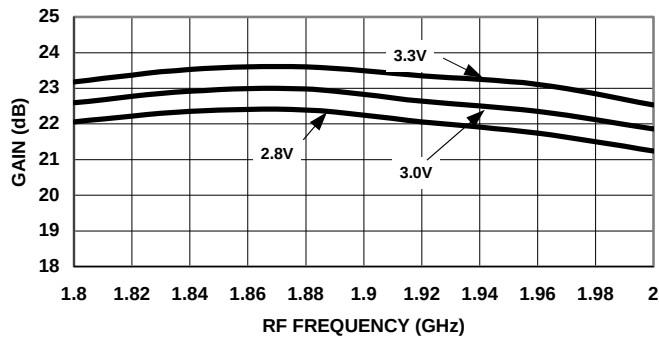
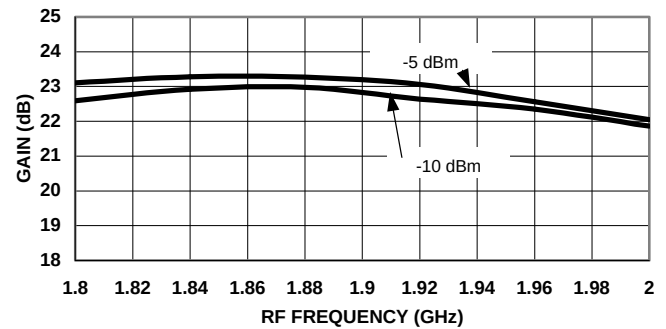
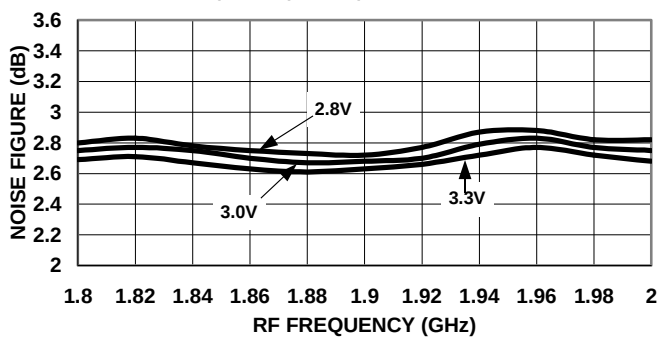
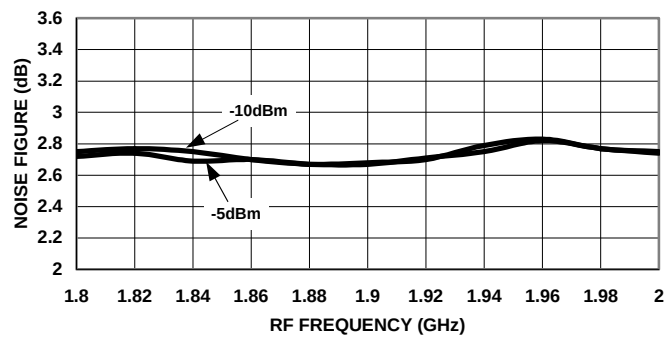
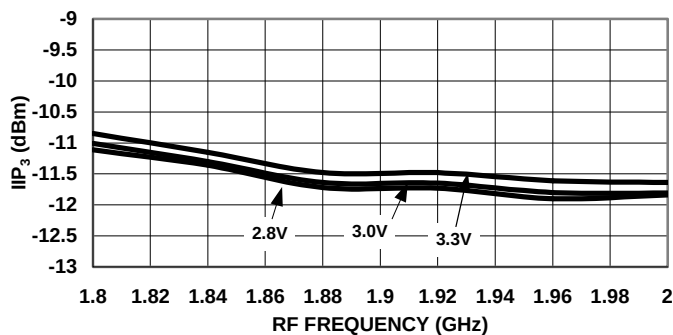
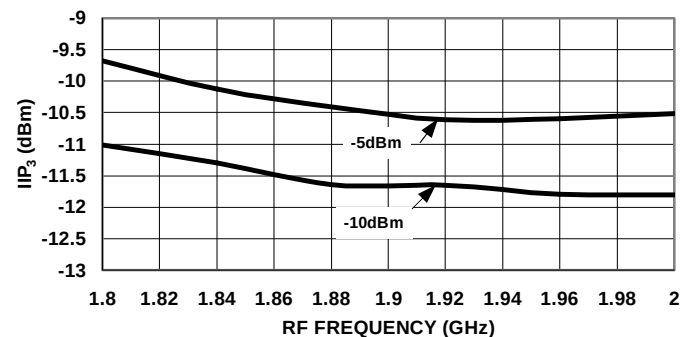
V 2.0

■ **North America:** Tel. (800) 366-2266, Fax (800) 618-8883
 ■ **Asia/Pacific:** Tel. +81-44-844-8296, Fax +81-44-844-8298
 ■ **Europe:** Tel. +44 (1344) 869 595, Fax +44 (1344) 300 020

Visit www.macom.com for additional data sheets and product information.

tyco / Electronics

MACOM

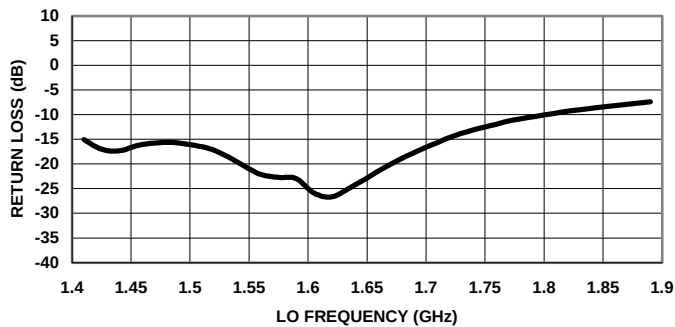
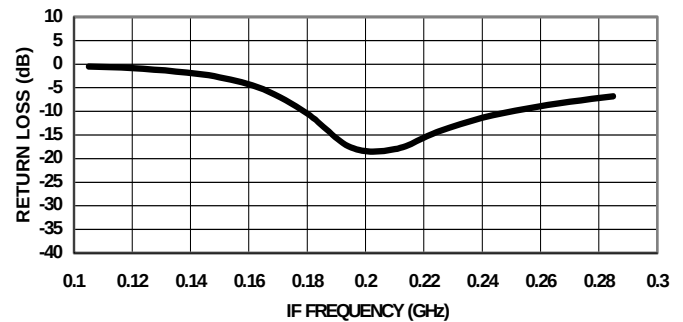
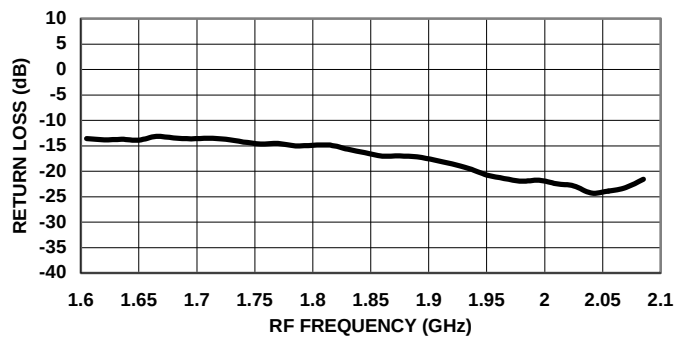
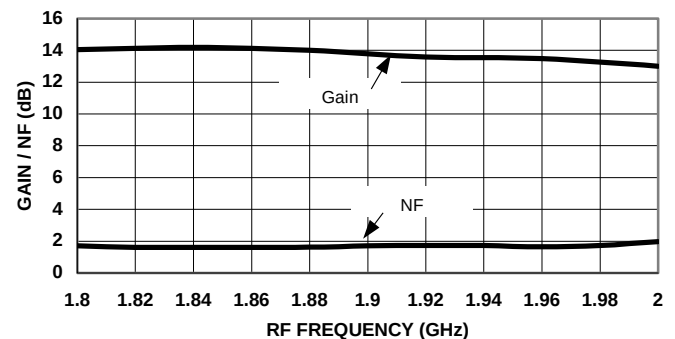
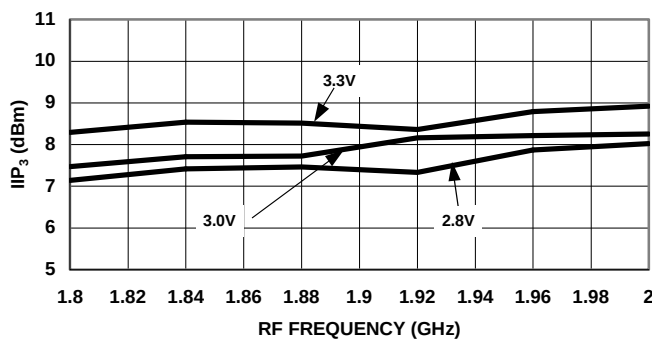
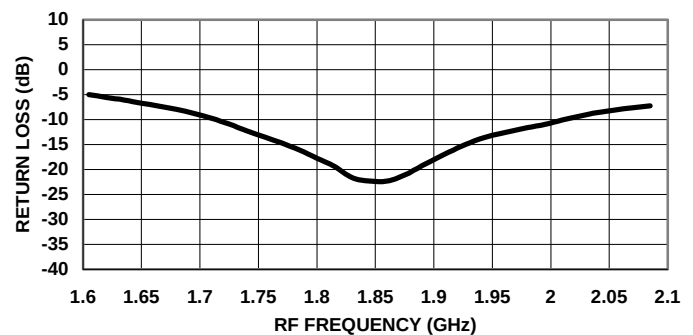
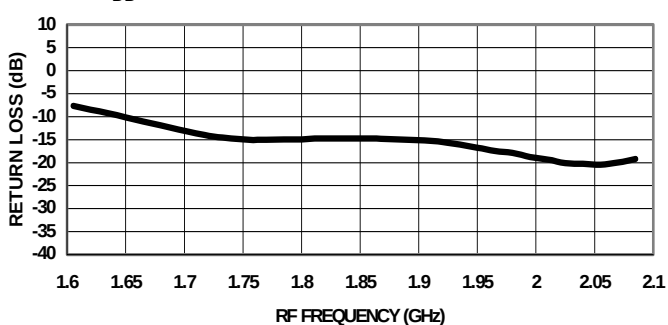
Typical Performance Curves LNA/Downconverter (with 3dB Pad in place of Image Reject Filter)**Conversion Gain vs. Frequency**
 $V_{DD} = 2.8V, 3.0V, 3.3V, LO = -10dBm$ **Conversion Gain vs. Frequency**
 $LO = -10 dBm, -5 dBm, V_{DD} = 3.0V$ **Noise Figure vs. Frequency**
 $V_{DD} = 2.8V, 3.0V, 3.3V, LO = -10dBm$ **Noise Figure vs. Frequency**
 $LO = -10dBm, -5dBm, V_{DD} = 3.0V$ **Input IP₃ vs. Frequency**
 $V_{DD} = 2.8V, 3.0V, 3.3V, LO = -10dBm$ **Input IP₃ vs. Frequency**
 $LO = -10dBm, -5dBm, V_{DD} = 3.0V$ 

Specifications subject to change without notice.

V 2.0

■ **North America:** Tel. (800) 366-2266, Fax (800) 618-8883
 ■ **Asia/Pacific:** Tel. +81-44-844-8296, Fax +81-44-844-8298
 ■ **Europe:** Tel. +44 (1344) 869 595, Fax +44 (1344) 300 020

Visit www.macom.com for additional data sheets and product information.**tyco** / Electronics**MACOM**

Typical Performance Curves LNA/Downconverter (with 3dB Pad in place of Image Reject Filter) Cont'd)**LO Input Return Loss vs. Frequency**
LO = -10dBm, $V_{DD} = 3.0V$ **IF Output Return Loss vs. Frequency**
LO = -10dBm, $V_{DD} = 3.0V$ **Downconverter Input Return Loss vs. Frequency**
LO = -10dBm, $V_{DD} = 3.0V$ **LNA Gain, Noise Figure vs. Frequency**
 $V_{DD} = 3.0V$ **LNA Input IP_3 vs. Frequency**
 $V_{DD} = 2.8V, 3.0V, 3.3V$ **LNA Input Return Loss vs. Frequency**
 $V_{DD} = 3.0V$ **LNA Output Return Loss vs. Frequency**
 $V_{DD} = 3.0V$ 

Specifications subject to change without notice.

V 2.0

■ North America: Tel. (800) 366-2266, Fax (800) 618-8883
 ■ Asia/Pacific: Tel. +81-44-844-8296, Fax +81-44-844-8298
 ■ Europe: Tel. +44 (1344) 869 595, Fax +44 (1344) 300 020

Visit www.macom.com for additional data sheets and product information.

tyco / Electronics

MACOM

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9